

### **Amendments to the Specification:**

Please amend paragraph [0034] as follows:

**[0034]** Further by way of example only, the porous oxide might comprise multiple cations. By way of example only, one such porous oxide comprises  $\text{In}_x\text{Sn}_y\text{O}$ , which is an electrically conductive oxide. By way of example only, exemplary indium and tin precursors are trimethyl tin and trimethyl indium. Such might be fed to the deposition chamber simultaneously in desired ratios towards achieving the desired quantity of tin and indium in the oxide being formed. Further by way of example only, such simultaneous feeding ~~might as~~ might be as a mixture or separately to the chamber. Further by way of example only, the tin containing precursor and the indium containing precursor might be fed to the deposition chamber at different times. Such different times might overlap with one another, or be spaced from one another such that there is no overlap.